

Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from, Europe, America and south Asia, supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of "Quality Parts, Customers Priority, Honest Operation, and Considerate Service", our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip, ALPS, ROHM, Xilinx, Pulse, ON, Everlight and Freescale. Main products comprise IC, Modules, Potentiometer, IC Socket, Relay, Connector. Our parts cover such applications as commercial, industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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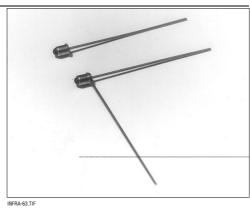




Silicon Phototransistor

FEATURES

- Compact, metal can coaxial package
- 24° (nominal) acceptance angle
- Wide sensitivity ranges
- Wide operating temperature range (- 55°C to +125°C)
- Mechanically and spectrally matched to SE1450 and SE1470 infrared emitting diodes



DESCRIPTION

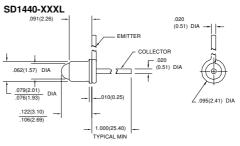
The SD1440 is an NPN silicon phototransistor mounted in a glass lensed metal can coaxial package. The package may have a tab or second lead welded to the can as an optional feature (SD1440-XXXL). Both leads are flexible and may be formed to fit various mounting configurations.

OUTLINE DIMENSIONS in inches (mm)

3 plc decimals ±0.005(0.12) 2 plc decimals ±0.020(0.51)

SD1440-XXX COLLECTOR .062(1.57) DIA

DIM_12a.ds4



DIM_12b.ds4

Honeywell

Honeywell reserves the right to make changes in order to improve design and supply the best products possible.

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ELECTRICAL CHARACTERISTICS (25°C unless otherwise noted)

PARAMETER	SYMBOL	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Light Current	lμ				mA	V _{CE} =5 V
SD1440-001, SD1440-001 L		0.7				H=5 mW/cm ^{2 (1)}
SD1440-002, SD1440-002 L		1.5				
SD1440-003, SD1440-003 L		3.0				
SD1440-004, SD1440-004 L		6.0				
Collector Dark Current	Iceo			100	nA	V _{CE} =10 V, H=0
Collector-Emitter Breakdown Voltage	V _(BR) CEO	30			V	Ic=100 μA
Emitter-Collector Breakdown Voltage	V _{(BR)ECO}	5.0			V	I _E =100 μA
Collector-Emitter Saturation Voltage	VCE(SAT)			0.4	V	Ic=0.4 mA
						H=5 mW/cm ²
Angular Response (2)	Ø		24		degr.	I _F =Constant
Rise And Fall Time	t _r , t _f		15		μs	Vcc=5 V, I _L =1 mA
						R _L =1000 Ω

Notes

- The radiation source is a tungsten lamp operating at a color temperature of 2870°K.
 Angular response is defined as the total included angle between the half sensitivity points.

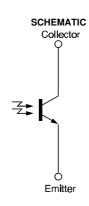
ABSOLUTE MAXIMUM RATINGS

(25°C Free-Air Temperature unless otherwise noted) Collector-Emitter Voltage 30 V Emitter-Collector Voltage 5 V Power Dissipation 75 mW (1) -55°C to 125°C Operating Temperature Range Storage Temperature Range -65°C to 150°C Soldering Temperature (10 sec) 260°C

Notes

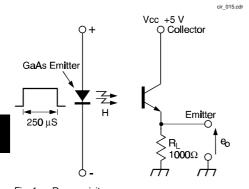
1. Derate linearly from 25°C free-air temperature at the rate of

0.71 mW/°C.



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SWITCHING TIME TEST CIRCUIT



SWITCHING WAVEFORM

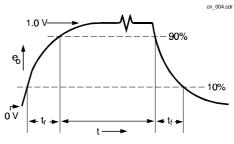


Fig. 1 Responsivity vs Angular Displacement 1.0

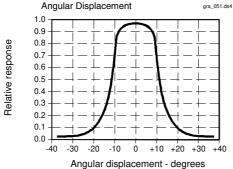


Fig. 2 Collector Current vs

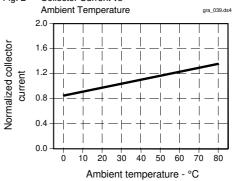
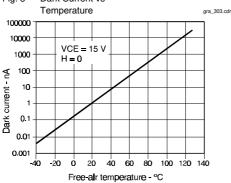
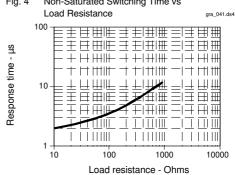


Fig. 3 Dark Current vs



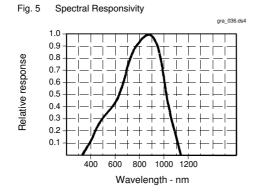
Non-Saturated Switching Time vs

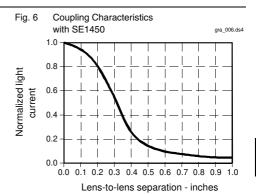


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All Performance Curves Show Typical Values